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Vishay Semiconductor/Diodes Division VESD05A1B-02V-GS08

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>





VESD05A1B-02V

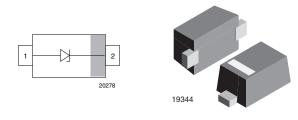
RoHS

COMPLIANT

<u>GREEN</u> (5-2008)**

Vishay Semiconductors

Single ESD-Protection Diode in SOD-523



MARKING (example only)



FEATURES• Single-line ESD-protection

- Capacitance typical $C_D = 12 \text{ pF}$ ($V_R = 2.5 \text{ V}, \text{ f} = 1 \text{ MHz}$)
- Leakage current $I_R < 1 \ \mu A \ (V_R = 5 \ V)$
- ESD-protection acc. IEC 61000-4-2 ± 20 kV contact discharge
- ± 20 kV contact discharge ± 30 kV air discharge
- e3 Sn
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Bar	=	ca	thode	marking

X = date code

Y = type code (see table below)

ORDERING INFORMAT	ORDERING INFORMATION			
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY	
VESD05A1B-02V	VESD05A1B-02V-G-08	3000	3000	

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05A1B-02V	SOD-523	.н	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	3	А		
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	33	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 20	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV		
Operating temperature	Junction temperature	T _J - 40 to + 125		°C		
Storage temperature		T _{stg}	- 55 to + 150	°C		

** Please see document "Vishay Material Category Policy": <u>www.vishay.com/doc?99902</u>



VESD05A1B-02V

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Single ESD-Protection Diode in SOD-523



BiAs

BIAs-MODE (bidirectional asymmetrical protection mode)

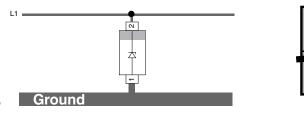
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With the VESD05A1B-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD05A1B-02V clamping behaviour is bidirectional and asymmetrical (BiAs).



ELECTRICAL CHARACTERISTICS VESD05A1B-02V							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines	
Reverse working voltage	at I _R = 1 μA	V _{RWM}	5	-	-	V	
Reverse current	at V _R = 5 V	I _R	-	0.01	0.1	μΑ	
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6	6.8	7.5	V	
Reverse clamping voltage	at I _{PP} = 1 A	V	-	8	9.5	V	
	at I _{PP} = I _{PPM} = 3 A	V _C	-	8.9	11	V	
Forward clamping voltage	at I _{PP} = 0.2 A		-	0.95	1.2	V	
	at I _{PP} = 1 A	V _F	-	1.3	-	V	
	at I _{PP} = I _{PPM} = 3 A]	-	1.9	-	V	
Capacitance	at V _R = 0 V; f = 1 MHz	<u> </u>	-	19	23	pF	
	at V _R = 2.5 V; f = 1 MHz	C _D	-	12	-	pF	

Note

Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 and pin 2).



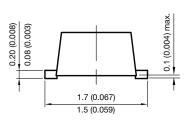


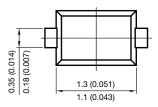
VESD05A1B-02V

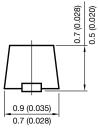
Single ESD-Protection Diode in SOD-523

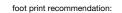
Vishay Semiconductors

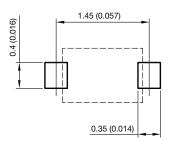
PACKAGE DIMENSIONS in millimeters (inches): SOD-523











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